# Low Power Bipolar Transistors



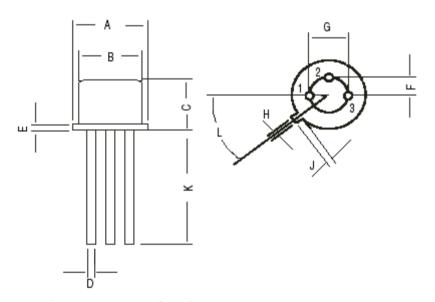
#### **TO-18**



#### Features:

NPN Silicon Planar Epitaxial Transistors. Suitable for applications requiring low noise and good  $h_{\text{FE}}$  linearity, eg. audio pre-amplifiers, and instrumentation.

## **TO-18 Metal Can Package**



Dimension	Minimum	Maximum		
Α	5.24	5.84		
В	4.52	4.97		
С	4.31	5.33		
D	0.40	0.53		
Е	-	0.76		
F	-	1.27		
G	-	2.97		
Н	0.91	1.17		
J	0.71	1.21		
K	12.70	-		
L	45°			

Dimensions: Millimetres



### **Pin Configuration**

- 1. Emitter.
- 2. Base.
- 3. Collector.

multicomp

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## **Absolute Maximum Ratings**

DESCRIPTION	SYMBOL	BC107	BC108	BC109	UNIT
Collector-Emitter Voltage	V <sub>CEO</sub>	45	25	25	V
Collector-Base Voltage	$V_{CBO}$	50	30	30	V
Emitter-Base Voltage	$V_{EBO}$	6.0	5.0	5.0	V
Collector Current Continuous	I <sub>C</sub>		0.2		Α
Power Dissipation at Ta = 25°C	$P_{D}$		0.6		W
Derate Above 25°C			2.28		mW/°C
Power Dissipation at Tc = 25°C	P <sub>D</sub>		1.0		W
Derate Above 25°C			6.67		mW/°C
Operating And Storage Junction	T <sub>j</sub> , T <sub>stg</sub>		-65 to -	<b>⊦</b> 200	°C
Temperature Range					
Thermal Resistance					
Junction to Case	R <sub>th (j-c)</sub>		175		°C/W

## **Electrical Characteristics (Ta = 25°C Unless Otherwise Specified)**

Description	Symbol	Test Condition		Minimum	Maximum	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	$I_{\rm C} = 2  \text{mA}, I_{\rm B} = 0$	BC107	45		V
		-	BC108/109	20		V
Emitter-Base Voltage	V <sub>EBO</sub>	I <sub>E</sub> = 10uA, I <sub>C</sub> = 0	BC107	6.0		V
			BC108/109	5.0		V
Collector-Cut off Current	І <sub>СВО</sub>	V <sub>CB</sub> = 45V, I <sub>E</sub> = 0	BC107		15	nA
	020	$V_{CB} = 25V, I_{E} = 0$ $T_{amb} = 125^{\circ}C$			15	nA
		$V_{CB} = 45V, I_{E} = 0$			4.0	uA
		$V_{CB} = 25V, I_{E} = 0$	BC108/109		4.0	uA







Description	Symbol	Test Condition	N	/linimum	Maximum	Unit
DC Current	h <sub>FE</sub>	I <sub>C</sub> = 10uA, V <sub>CE</sub> = 5V	B Group	40		
	1.2	0 . 02	C Group	100		
		I <sub>C</sub> = 2mA, V <sub>CE</sub> = 5V	BC107	110	450	
		0 4 02	BC108	110	800	
			BC109	200	800	
			A Group	110	220	
			B Group	200	450	
			C Group	420	800	
Base Emitter Saturation Voltage	V <sub>BE (Sat)</sub>	Ic = 10mA, I <sub>B</sub> = 0.5mA			0.83	V
	,	Ic = 100mA, $IB = 5mA$			1.05	V
Collector Emitter Saturation Voltage	ge V <sub>CE (Sat)</sub>	Ic = 10mA, I <sub>B</sub> = 0.5mA			0.25	V
		$Ic = 100mA, I_B = 5mA$			0.60	V
Base Emitter on Voltage	V <sub>BE (on)</sub>	Ic = 2mA, V <sub>CE</sub> = 5V		0.55	0.70	V
		$Ic = 10mA, V_{CE} = 5V$			0.77	V
Collector Knee Voltage	V <sub>CE (K)</sub>	<del>-</del>	Ic = 10mA, I <sub>B</sub> = The Value for 0.60		0.60	V
		which Ic = 11mA, at V <sub>CE</sub>				
Transition Frequency	f <sub>t</sub>	$V_{CE}$ = 5V, IC =10mA, f =		MHz		
Noise Figure	NF	$V_{CE} = 5V, I_{C} = 0.2mA$				
		$R_g = 2$ kohms,				
		F = 30Hz to 15 KHz	BC109		4.0	dB
		F = 1kHz, $B = 200Hz$	BC109		4.0	dB
			BC107/10	8	10	dB
Output Capacitance	C <sub>obo</sub>	$V_{CB}$ = 10V, f = 1MHz			4.5	pF
0	1.	ALL f = 1kHz	D0407	405	500	
Small Signal Current Gain	$h_{FE}$	$I_C = 2mA, V_{CE} = 5V$	BC107	125	500	
			BC108	125	900	
			BC109	240	900	
			A Group	125	260	
			B Group	240	500	
			C Group	450	900	
		ALL f = 1kHz				
Input Impedance	hie	$I_C = 2mA, V_{CE} = 5V$	A Group	1.6	4.5	$K\Omega$
			B Group	3.2	8.5	$K\Omega$
			C Group	6.0	15	ΚΩ
Output Admittance	hoo	ALL $f = 1kHz$	A C		20	و ما مدر ر
Output Admittance	hoe	$I_C = 2mA, V_{CE} = 5V$	A Group		30	umhos
			B Group		60	umhos
			C Group		110	umhos



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## **Specifications**

V <sub>CEO</sub> maximum (V)	V <sub>CBO</sub> maximum (V)	I <sub>C</sub> maximum (A)	h <sub>FE</sub> minimum at I <sub>C</sub> = 2 (mA)	Noise Figure maximum (dB)	Transition Frequency minimum (MHz)	P <sub>tot</sub> at T <sub>a</sub> = 25°C (mW)	Package and pin out	Part Number (NPN)
			125	10	150	600	TO-18	BC107
45	50	50						BC107A
	25 30							BC107B
		0.2						BC108
								BC108B
25								BC108C
25			240	4				BC109
								BC109B
							BC109C	



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AUSTRALIA - Farnell InOne Tel No: ++ 61 2 9645 8888

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## ΜΑΙ ΑΥSΙΑ.

Tel No: ++ 60 3 7873 8000



#### SWEDEN - Farnell InOne

Tel No: ++ 46 8 730 50 00 Fax No: ++ 46 8 83 52 62

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